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L1: (2) "20040042298"
L2: (2) "6545903"
L3: (42946) phase adj change$5
L4: (9489) 3 and memory
L5: (62373) barrier adj layer
L6: (1198) metal adj barrier adj layer$1
L7: (4) 6 and 4
L8: (158) ovonic and memory
L9: (34) 5 and 8
L10: (687) GTS
L11: (1) 4 and 5 and 10
L12: (9) 4 and GTS
L13: (0) 8 and 6
L14: (4) 4 and 6
L15: (234) 4 and 5
L16: (50) niride
L17: (28440) Titanium adj nitride
L18: (77) 15 and 17
L19: (17526) common adj source
L20: (5) common adj source adj plug
L21: (289) 19 and memory and transistor and plug
Failed

DBs:   USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB
Default operator   OR

19 and memory and transistor and plug

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| | U | 1 | Document ID | Issue Date | Pages | Title | Current OR | Current XRef | Retrieval Cla | Inventor | S | C | P | 2 | 3 | Image I |
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